

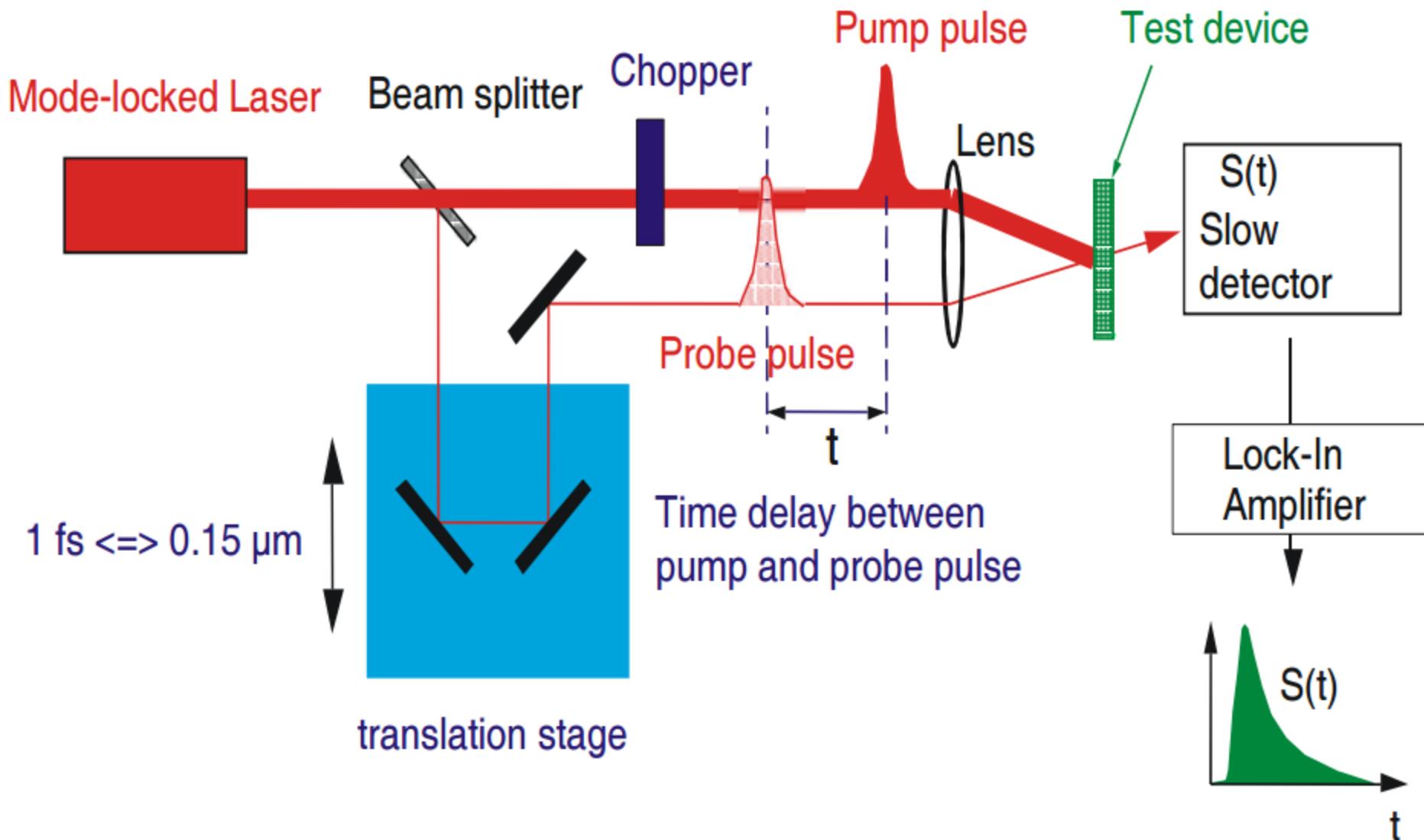
Dr. Katalin Kamarás (Wigner, SZFI) kamaras.katalin@wigner.hu  
Dr. Sándor Bordács (BME, FT) bordacs.sandor@wigner.bme.hu

# Optical Spectroscopy in Materials Science

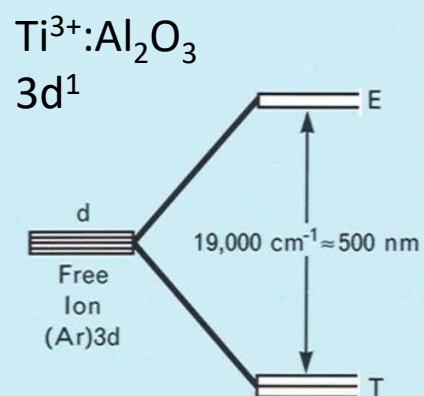
## Time-resolved spectroscopy



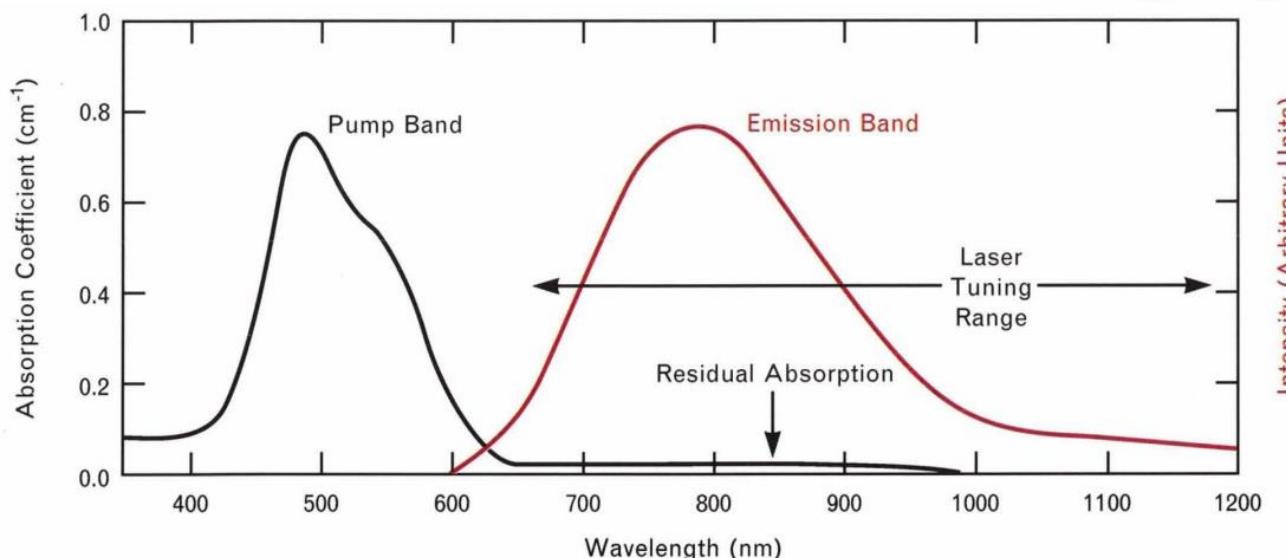
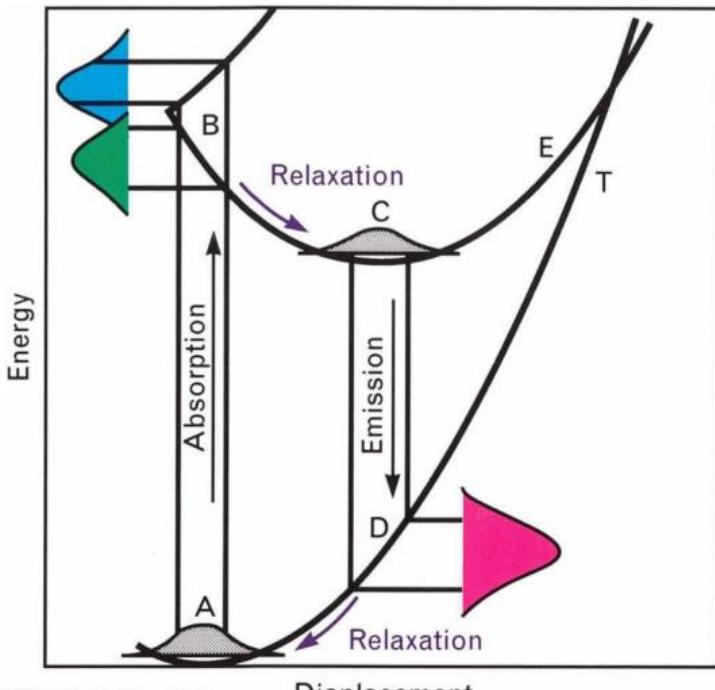
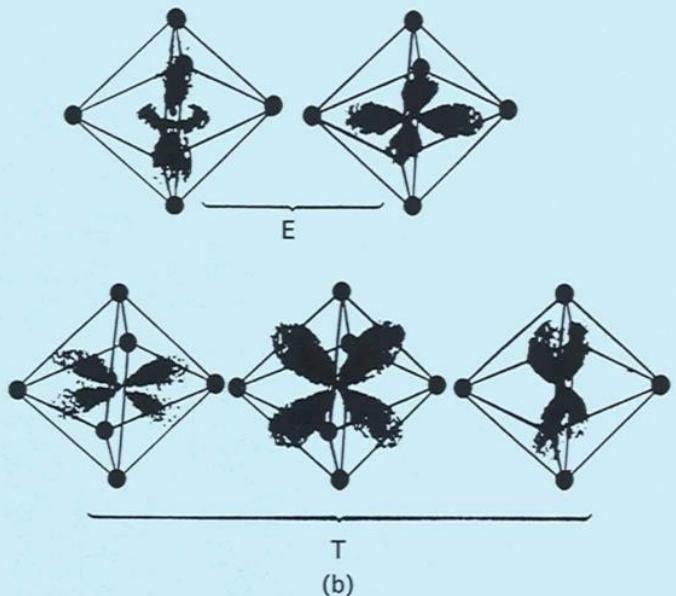
# Time-resolved absorption/reflectivity/luminescence ...



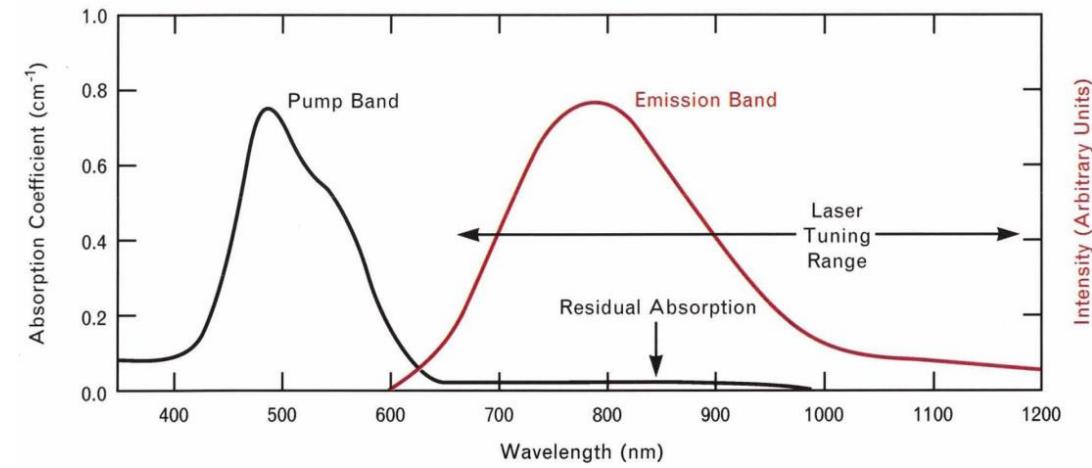
# Ti:sapphire LASER



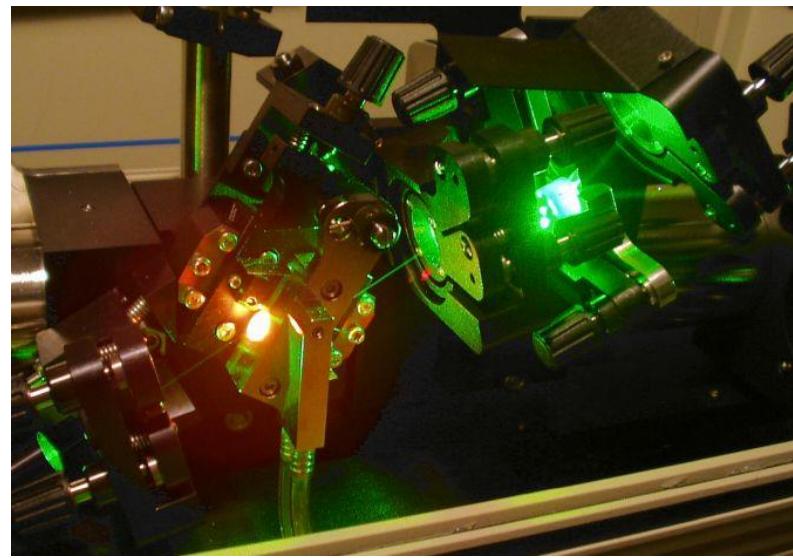
Cubic Potential  
(a)



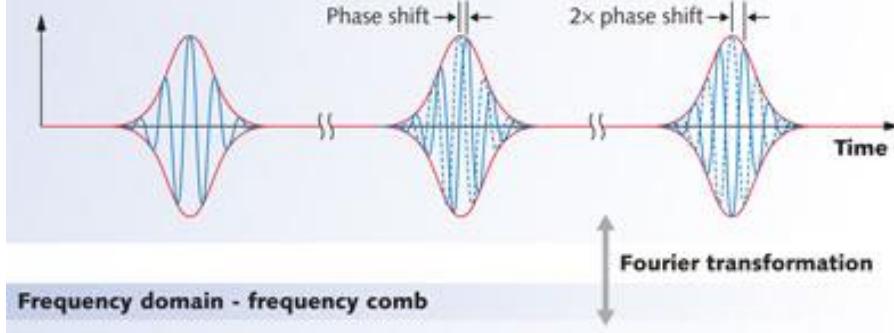
# Ti:sapphire LASER



Pump: green, lasing: NIR



Time domain - femtosecond pulses

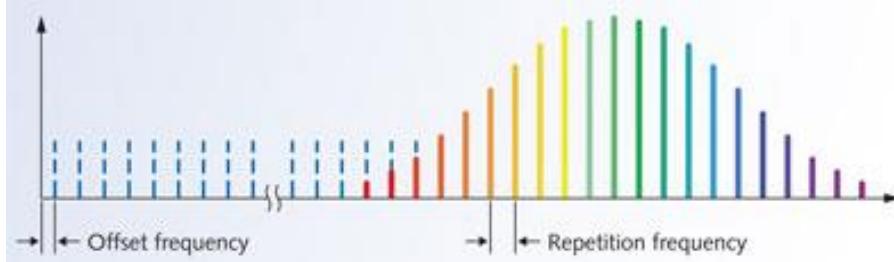


Central wavelength: 800 nm (375 THz)

Pulse width: 10-100 fs

Repetition rate: 80 MHz ( $\frac{c}{2L}$ ), resonator: ~2 m

Frequency domain - frequency comb

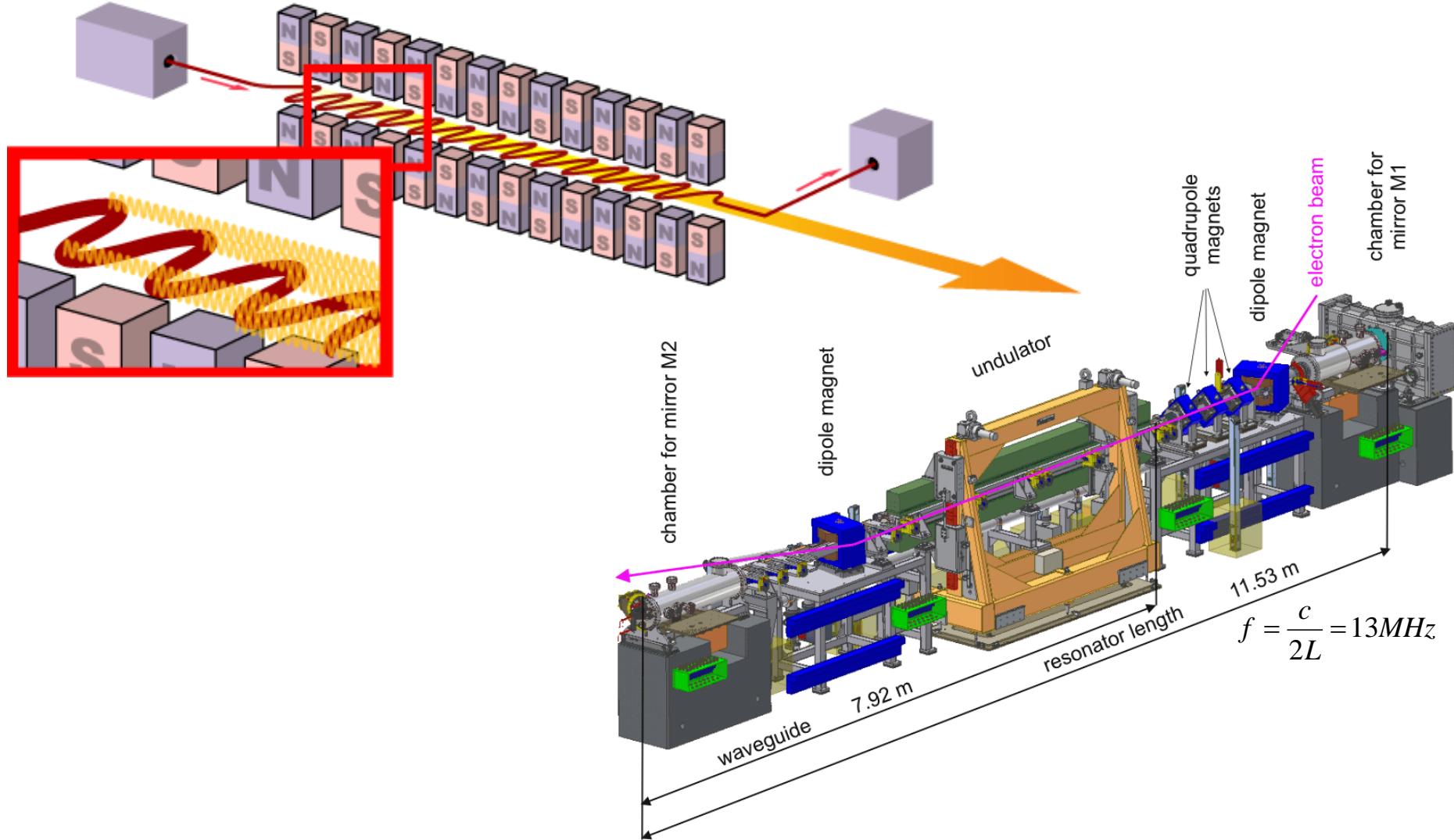


# Free Electron LASER (FEL)

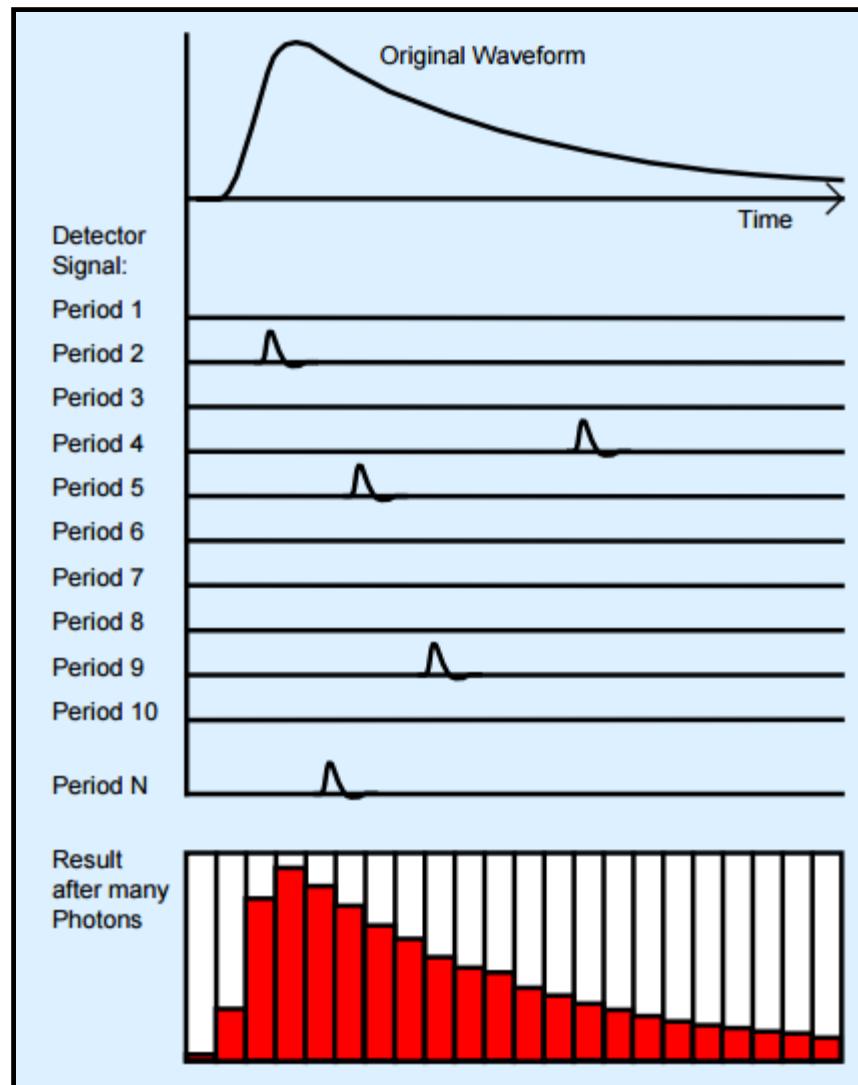
Lasing medium: relativistic free electrons traveling in an undulator

Interaction between the electron beam and the E-field of the radiation leads to bunching and coherent radiation

Most widely tuneable LASER: from microwave to X-ray



# Time-Correlated Single Photon Counting



# Ahmed Zewail - Facts



Ahmed H. Zewail

Born: 26 February 1946, Damanhur, Egypt

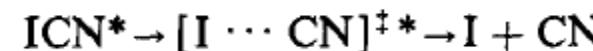
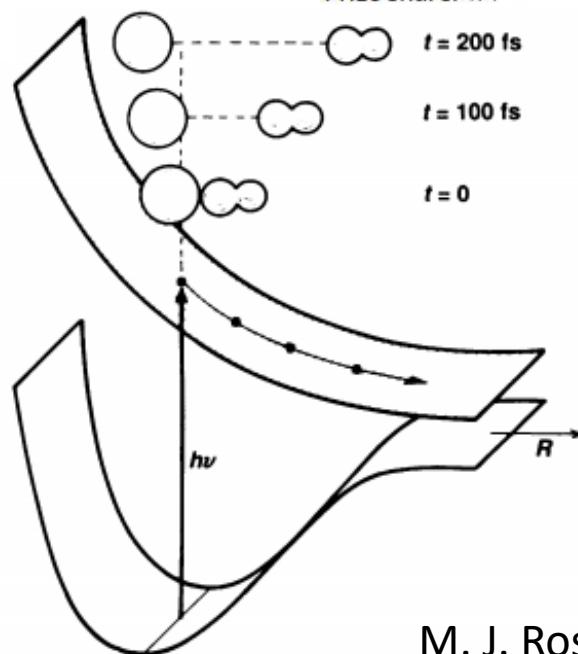
Died: 2 August 2016

Affiliation at the time of the award: California Institute of Technology (Caltech), Pasadena, CA, USA

Prize motivation: "for his studies of the transition states of chemical reactions using femtosecond spectroscopy"

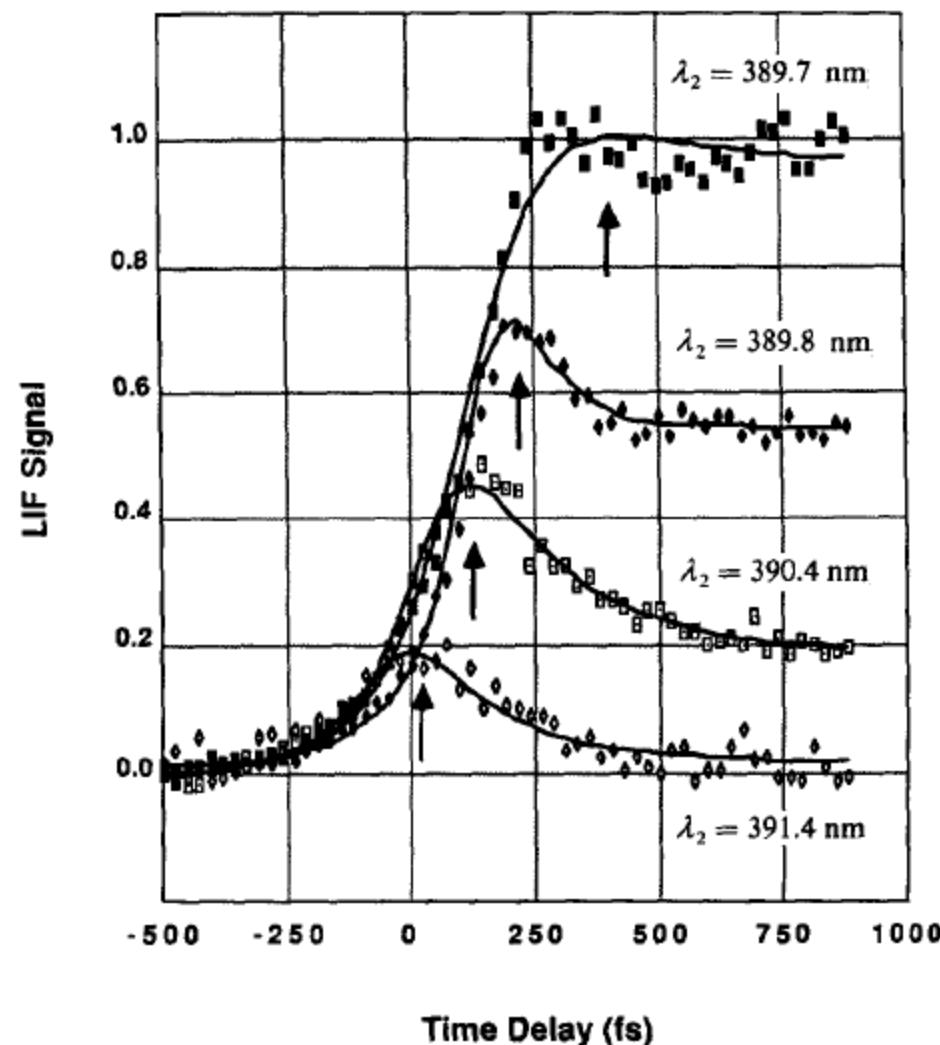
Field: chemical kinetics, physical chemistry

Prize share: 1/1

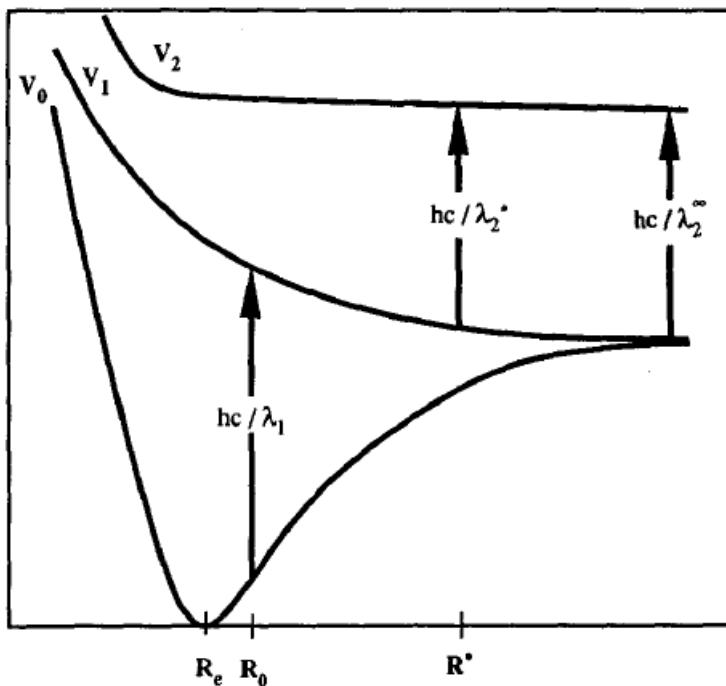


LIF: Laser Induced Fluorescence

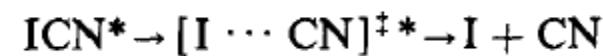
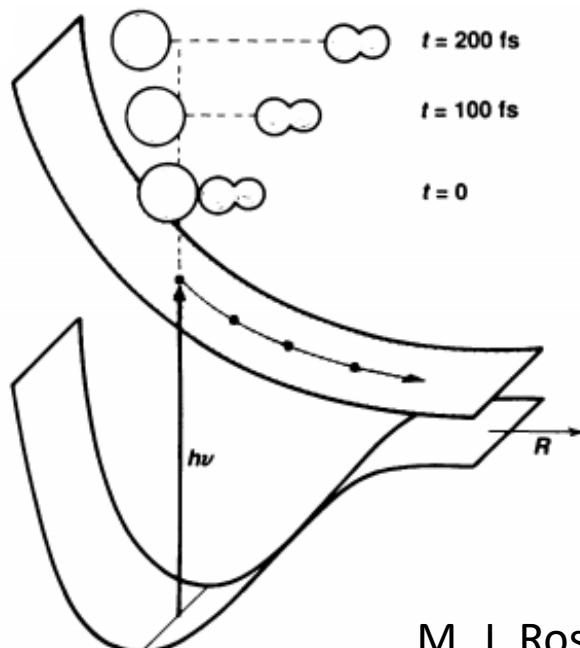
Fluorescence signal is measured after absorption



Potential Energy

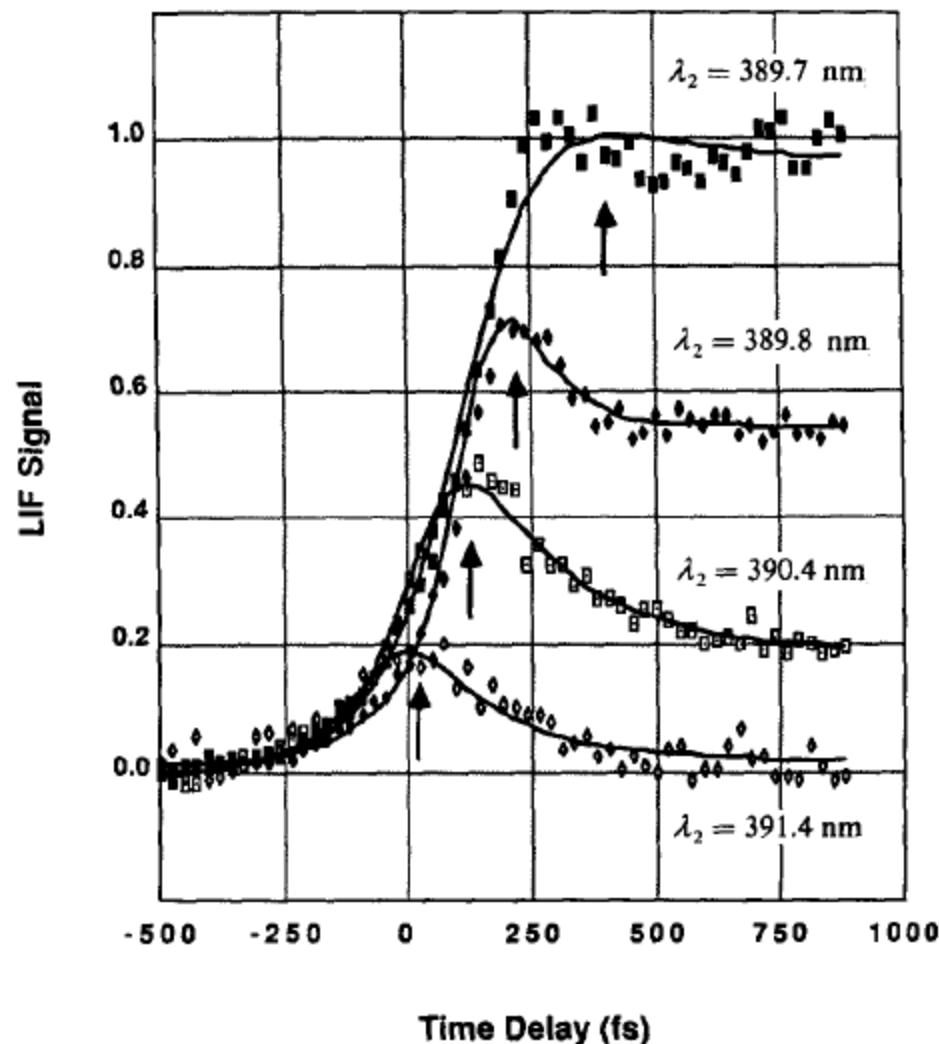


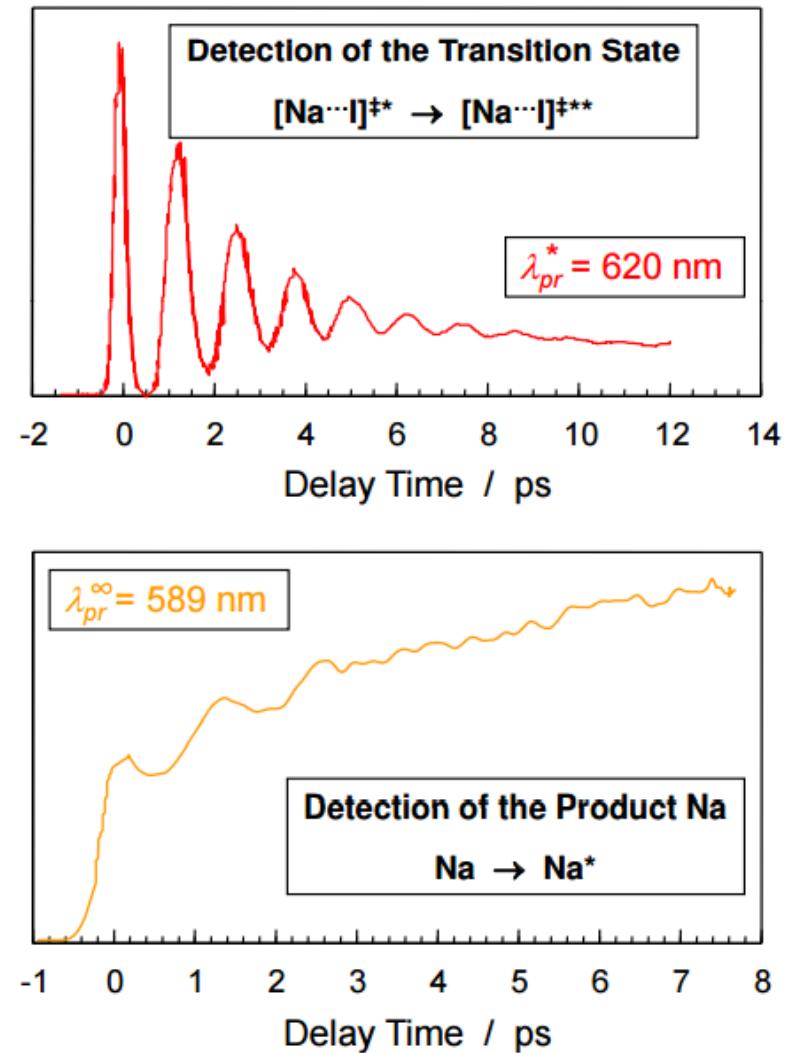
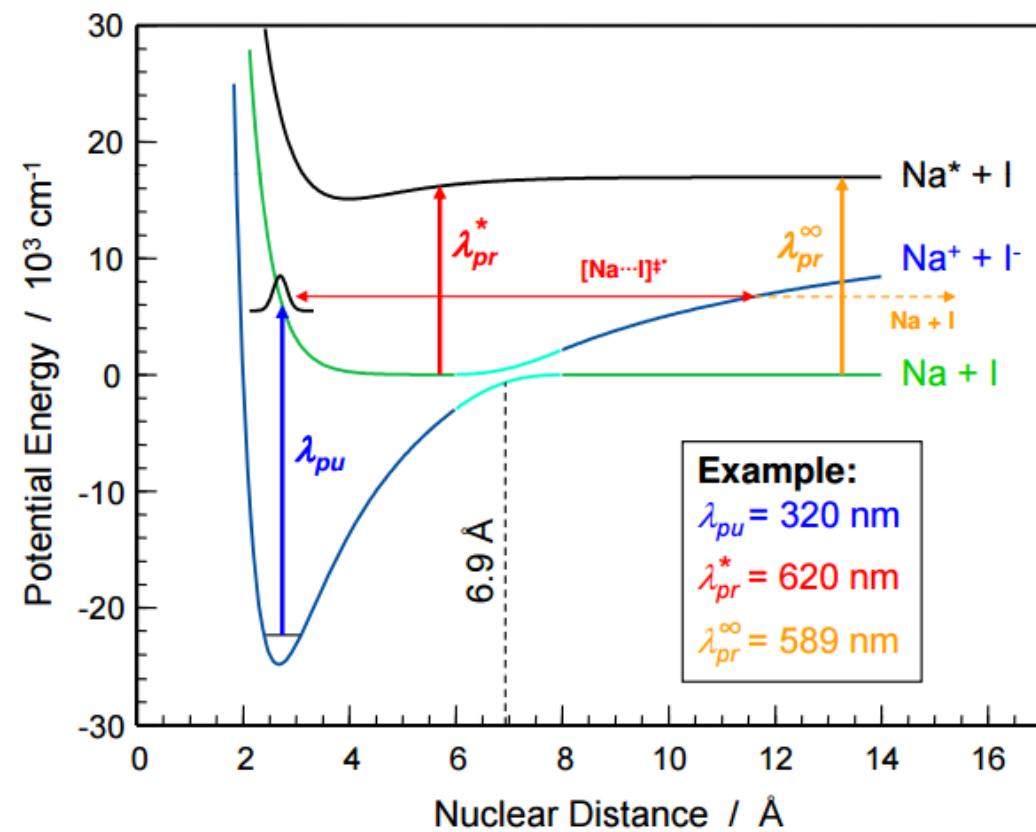
**Internuclear Separation**



LIF: Laser Induced Fluorescence

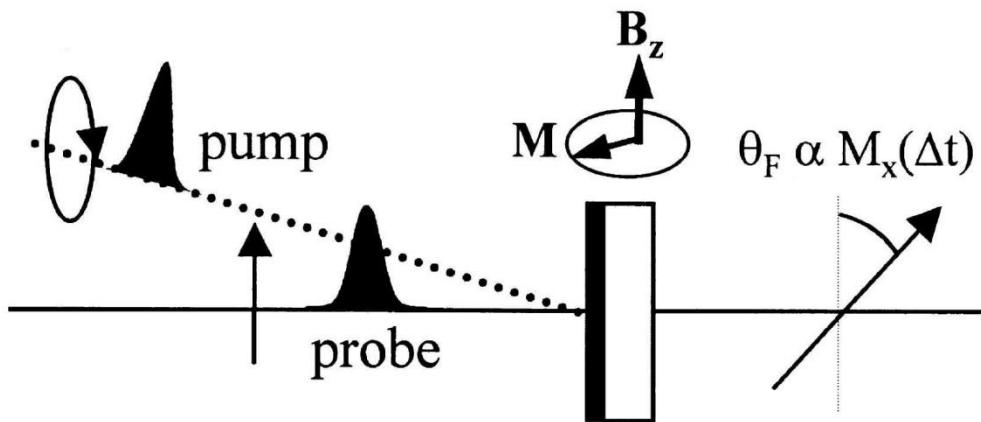
Fluorescence signal is measured after absorption



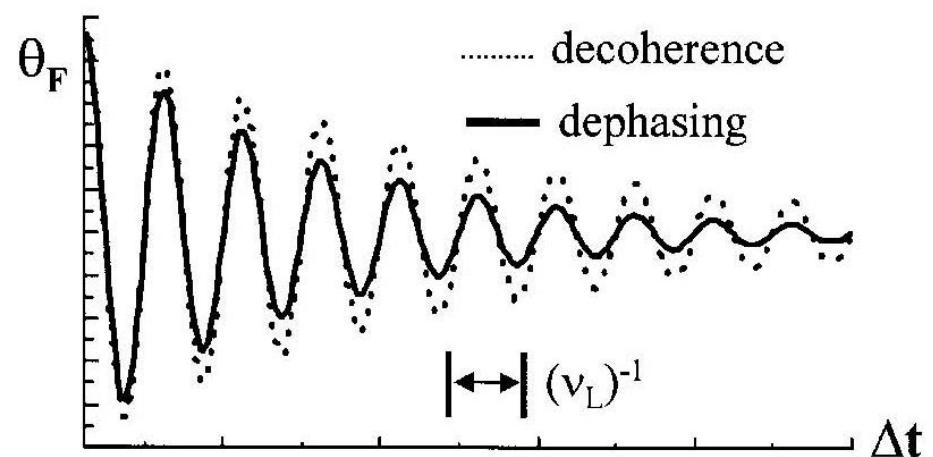


M. J. Rosker, M. Dantus, A. H. Zewail, J. Chem. Phys. **89**, 6113 (1988).  
A. Materny, Jacobs University Bremen (2009).

# Time-domain magneto-optical spectroscopy



$$\theta_F(\Delta t) = A e^{-\Delta t/T_2^*} \cos(2\pi v_L \Delta t)$$



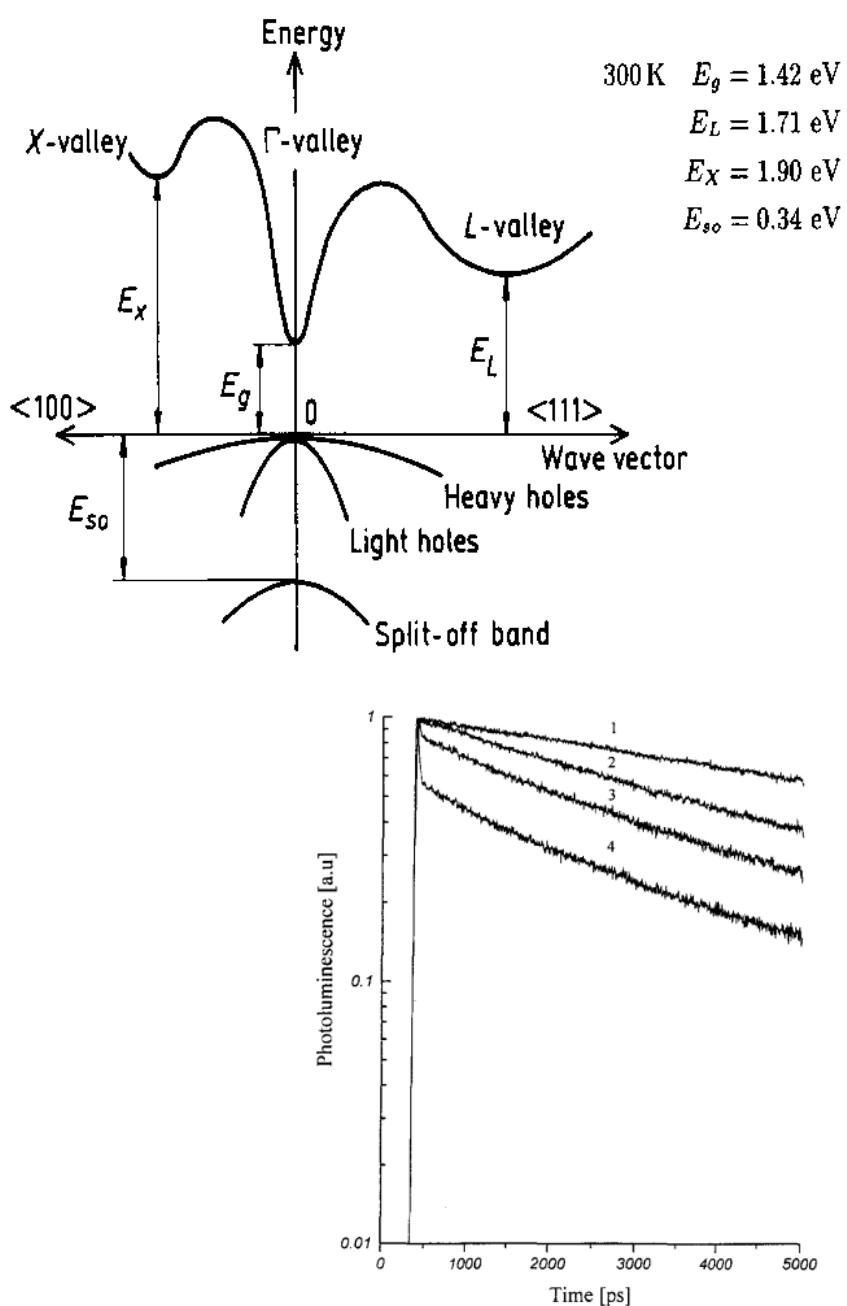
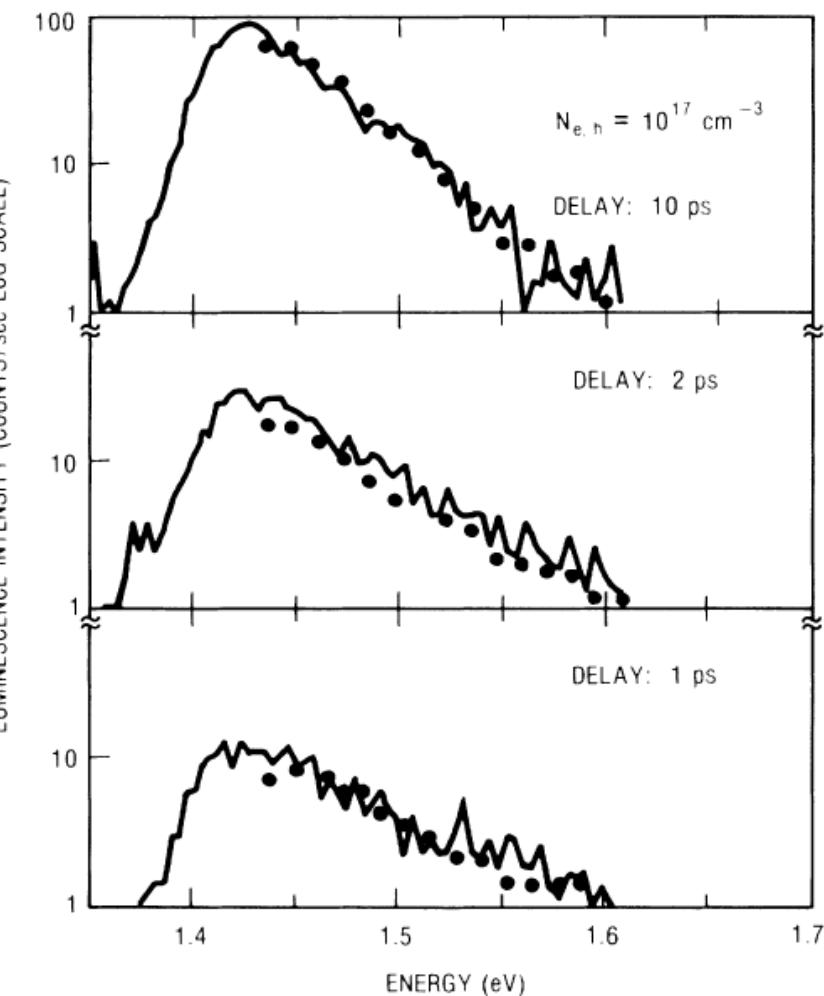
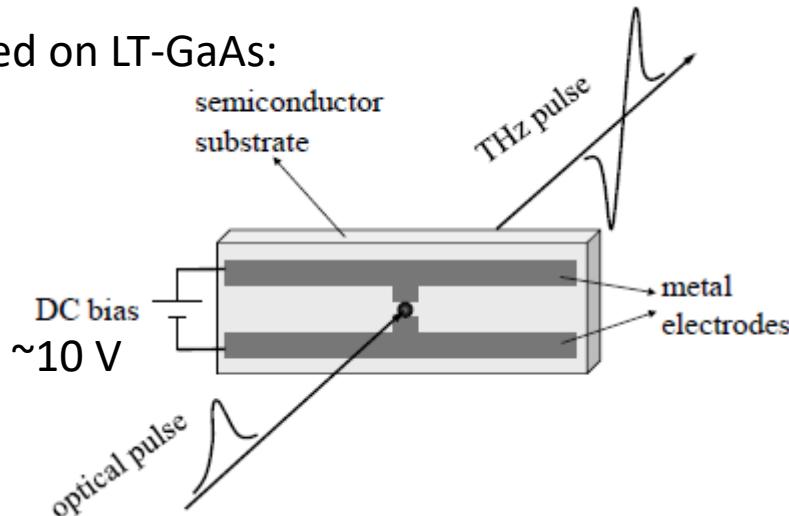


Fig. 1. Semilog plots of time resolved photoluminescence (PL) measured at various photon energies of  $0.5 \mu\text{m}$  GaAs crystal. Curves 1, 2, 3 and 4 correspond to PL energy of: 1.43 eV, 1.49 eV, 1.57 eV, 1.65 eV, respectively.



# THz spectroscopy: THz source

Dipole antenna fabricated on LT-GaAs:



LT-GaAs:

- recombination:  $\tau_{rec}=0.3$  ps
- mobility:  $\mu=200$  cm<sup>2</sup>/Vs ( $\tau_{scat}=30$  fs)
- gap:  $E_g=840$  nm

Ti:Sapphire LASER:

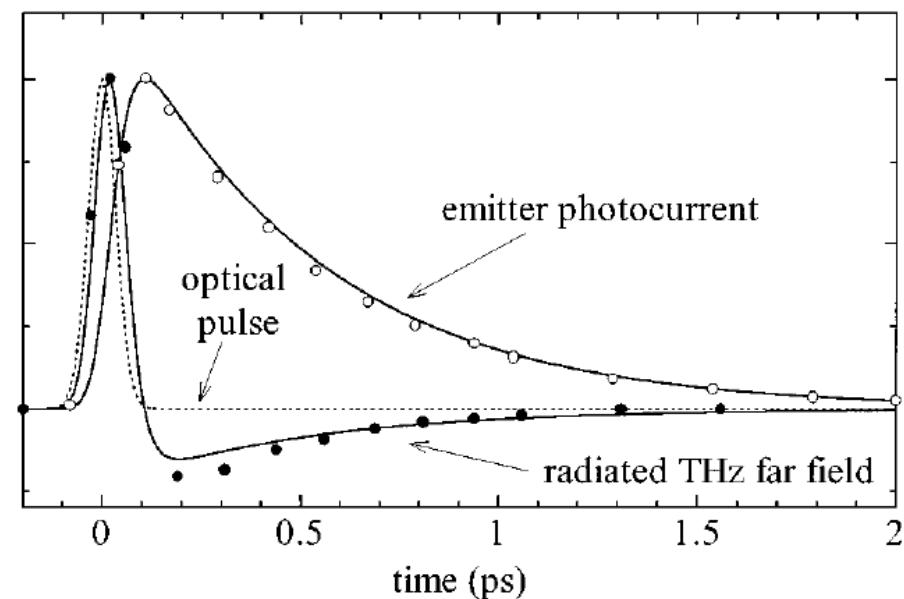
- central wavelength:  $\lambda=800$  nm
- pulse width:  $\tau<100$  fs

$$E_{THz} \propto \frac{\partial j}{\partial t}$$

$$j(t) = \int P(t-t')[en(t')v(t')]dt'$$

$$[...] = e \exp(-t'/\tau_{rec}) \mu (1 - \exp(-t'/\tau_{scat})) \frac{V}{d}$$

$$\nu_{Max} \sim \frac{1}{\tau_{rec}} = 3 \text{ THz}$$

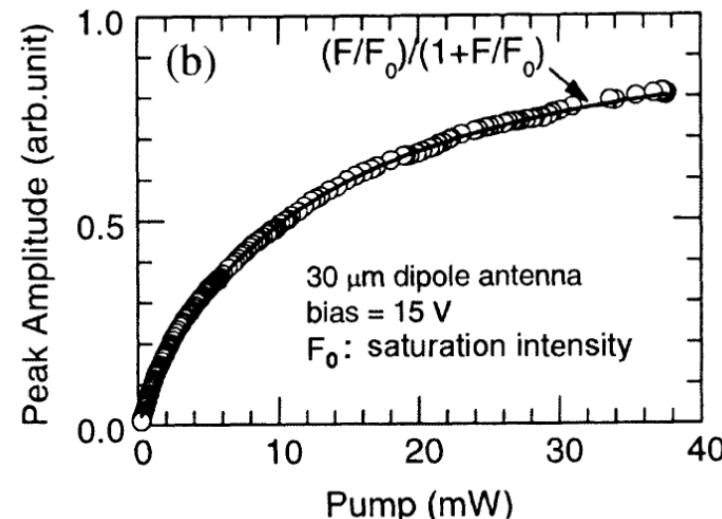
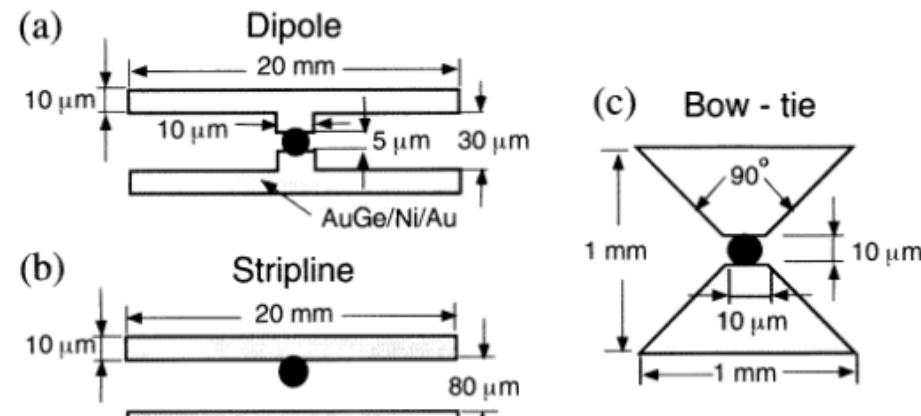
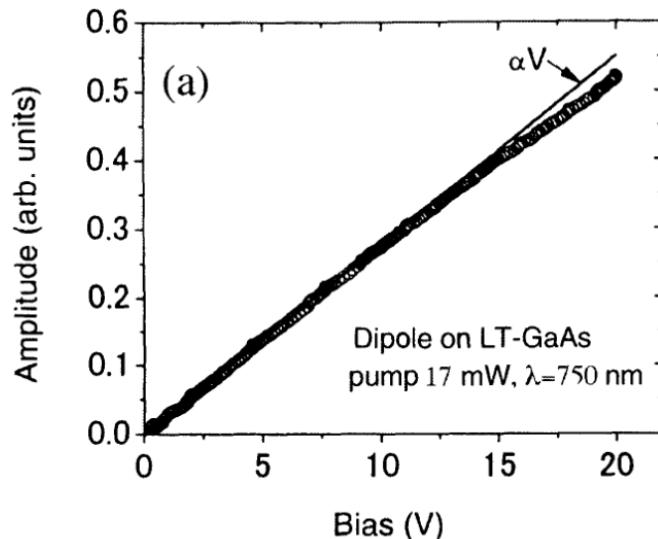
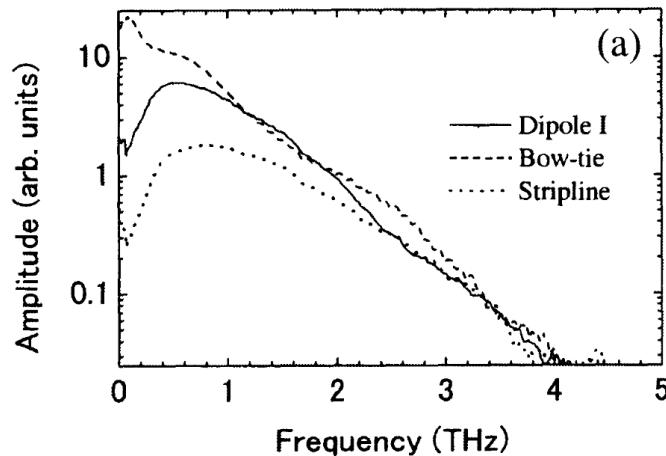


# THz spectroscopy: THz source

Ti:Sapphire  
@ 800nm  
20 mW

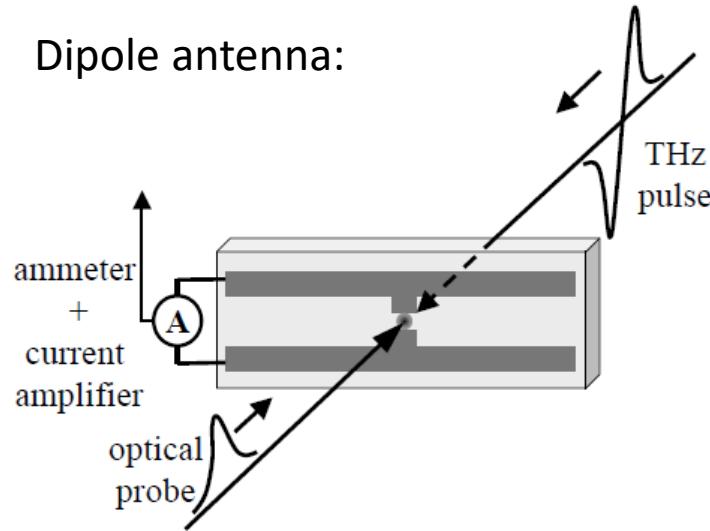
$\xrightarrow{60\text{ V}}$

THz radiation  
 $2\text{-}3\text{ }\mu\text{W}$

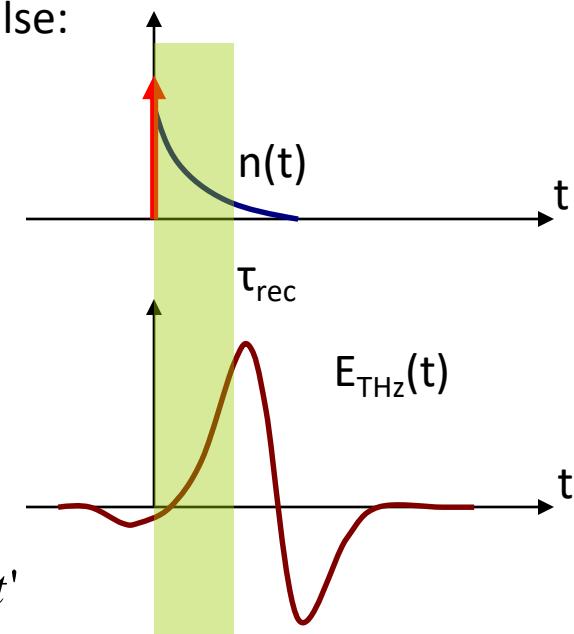


# THz spectroscopy: time-resolved detection

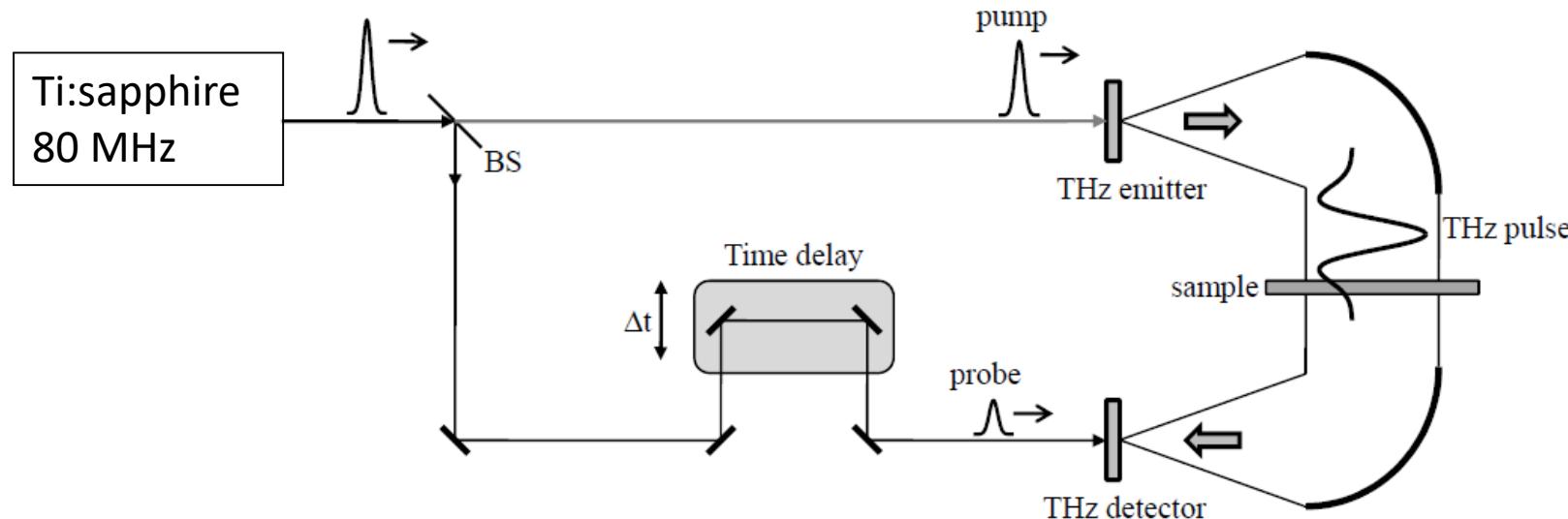
Dipole antenna:



$\delta$ -pulse:

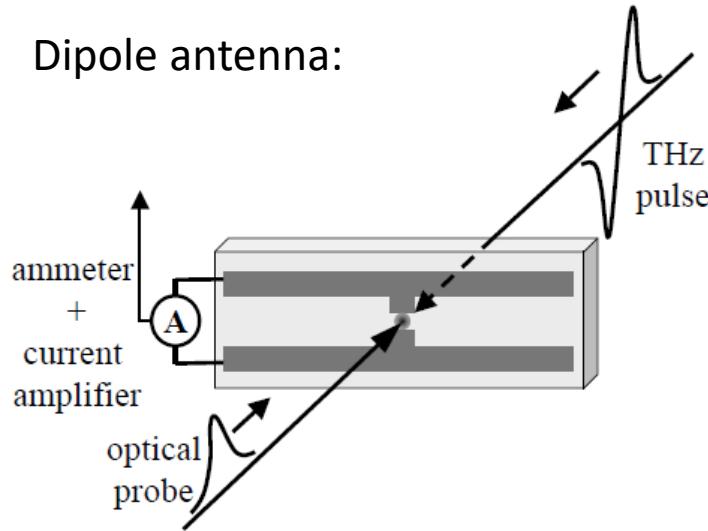


$$j_D(t) = e \exp(-t / \tau_{rec}) \int_0^t \exp(-t' / \tau_{scat}) \frac{e}{m} E_{THz}(t - t') dt'$$

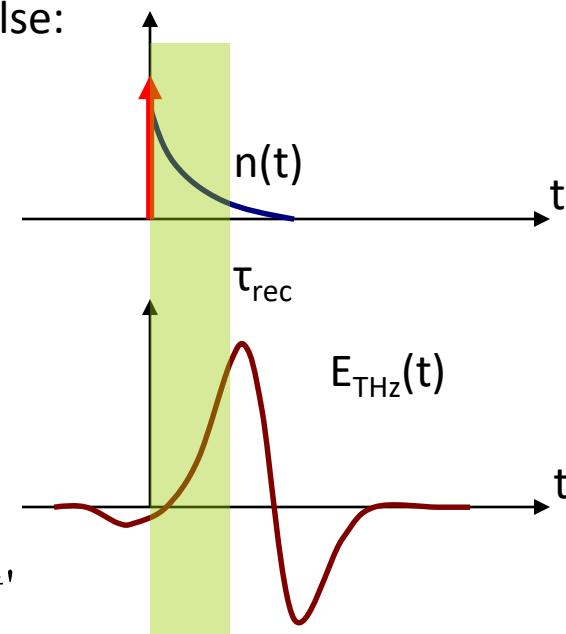


# THz spectroscopy: time-resolved detection

Dipole antenna:



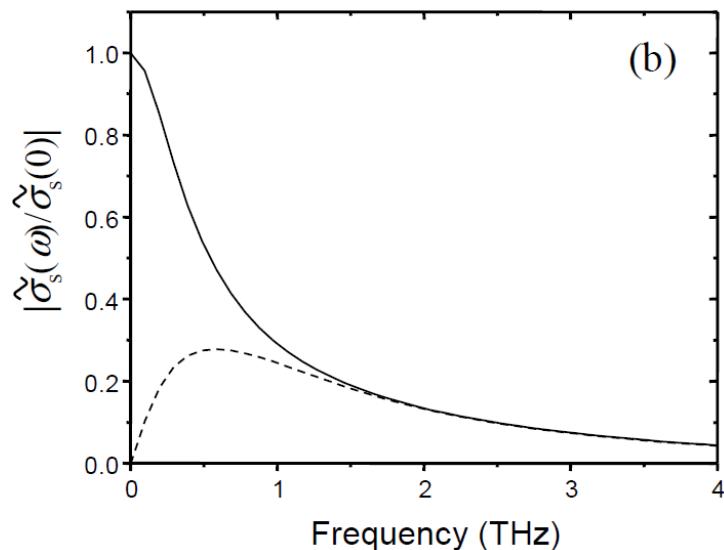
$\delta$ -pulse:



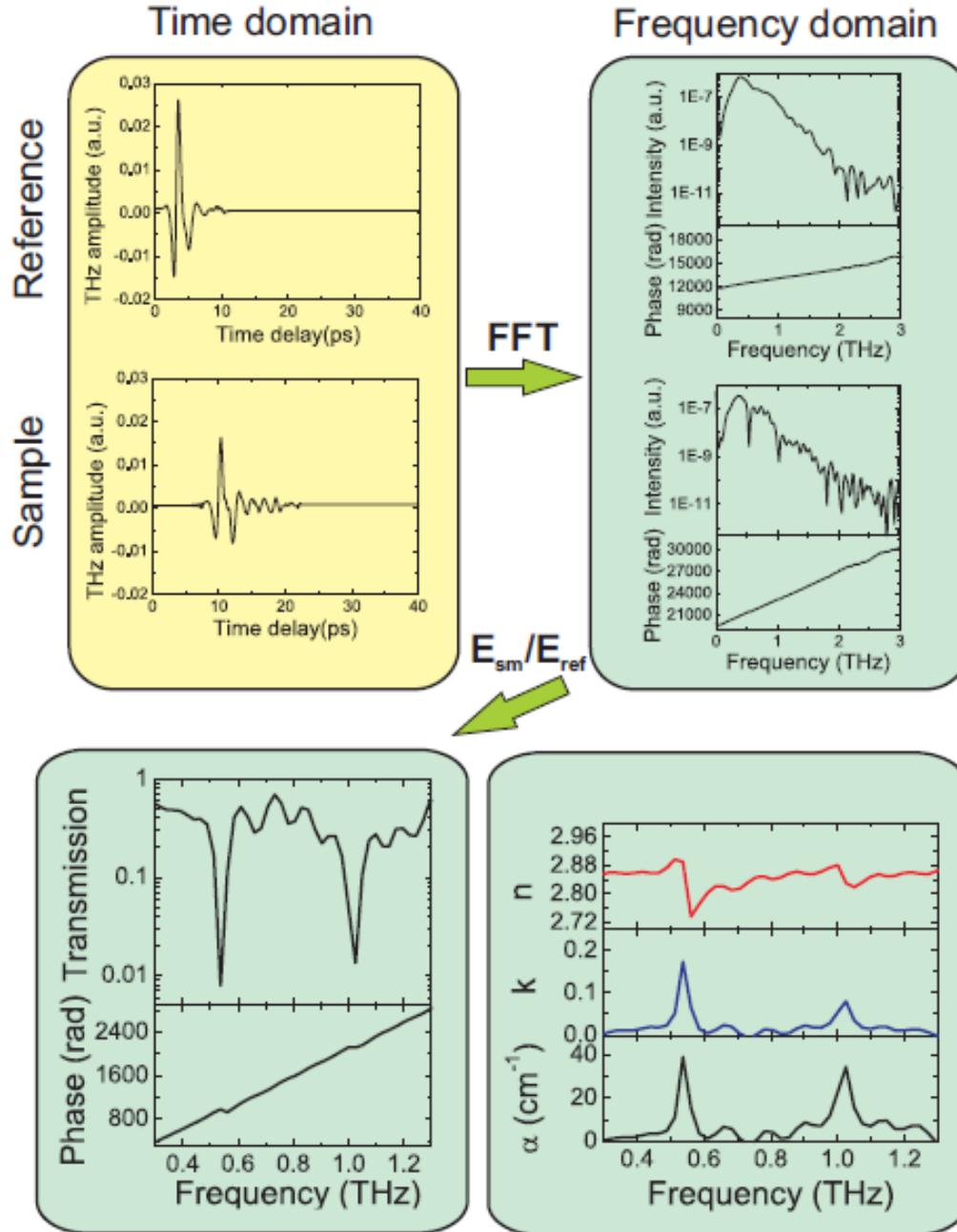
$$j_D(t) = e \exp(-t / \tau_{rec}) \int_0^t \exp(-t' / \tau_{scat}) \frac{e}{m} E_{THz}(t - t') dt'$$

High-frequency cut-off:  $1/\tau_{rec} \sim 3..7$  THz

Low-frequency cut-off: diffraction limited



# THz spectroscopy: full complex THz spectrum

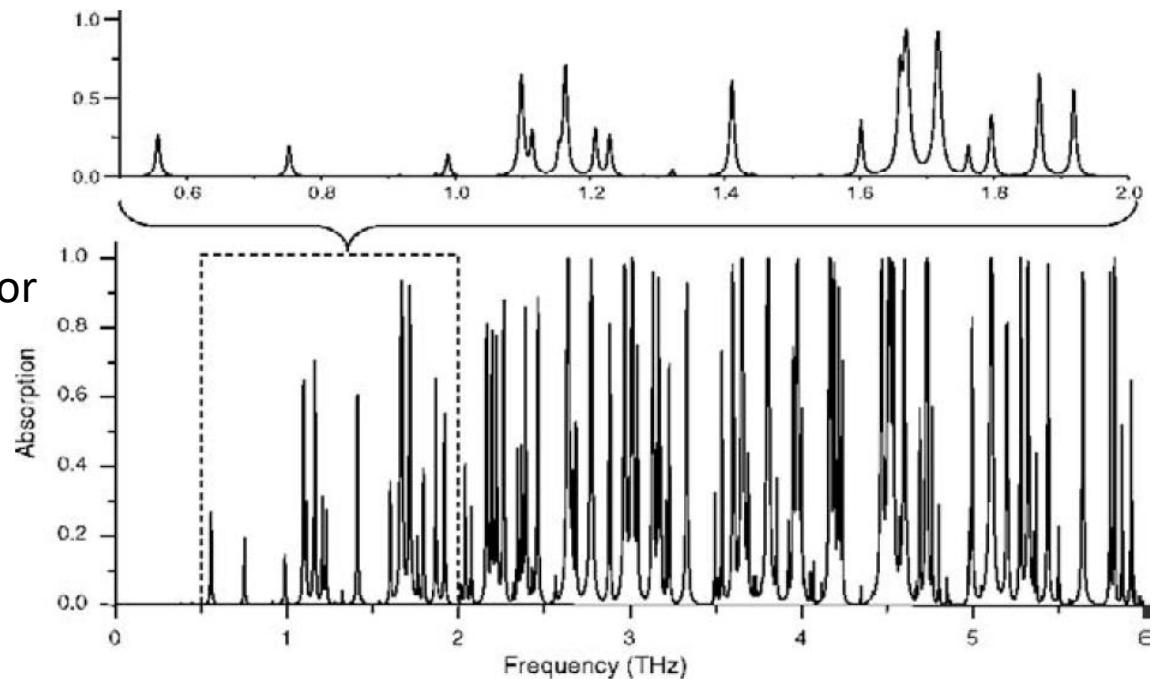


# THz fingerprints of molecules: rotational transitions

Molecular rotational energy:

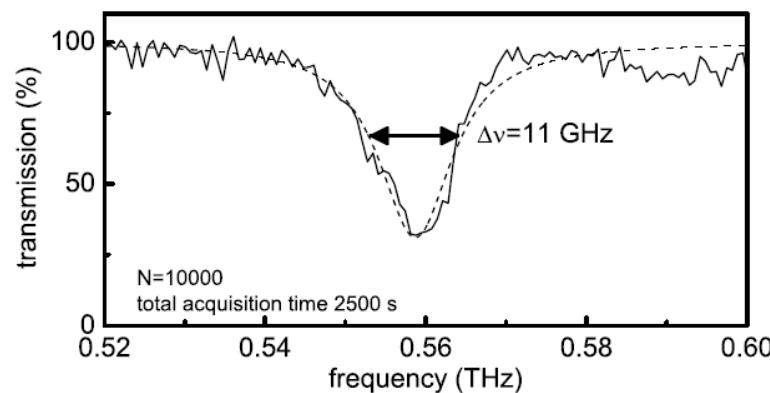
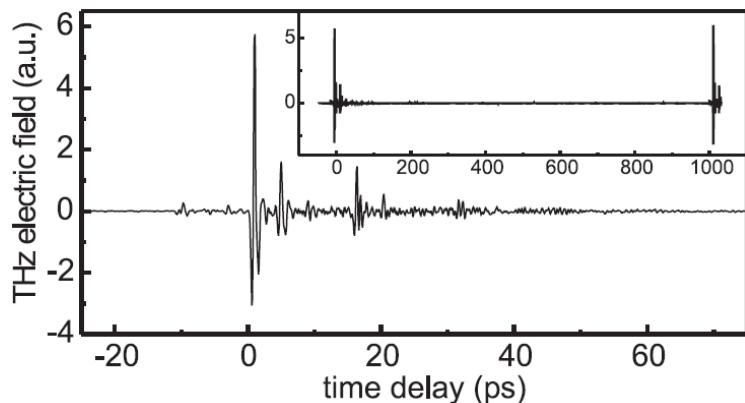
$$E \sim \frac{\hbar^2}{2MR^2} \sim 1\text{ THz}$$

Rotational spectrum of water vapor



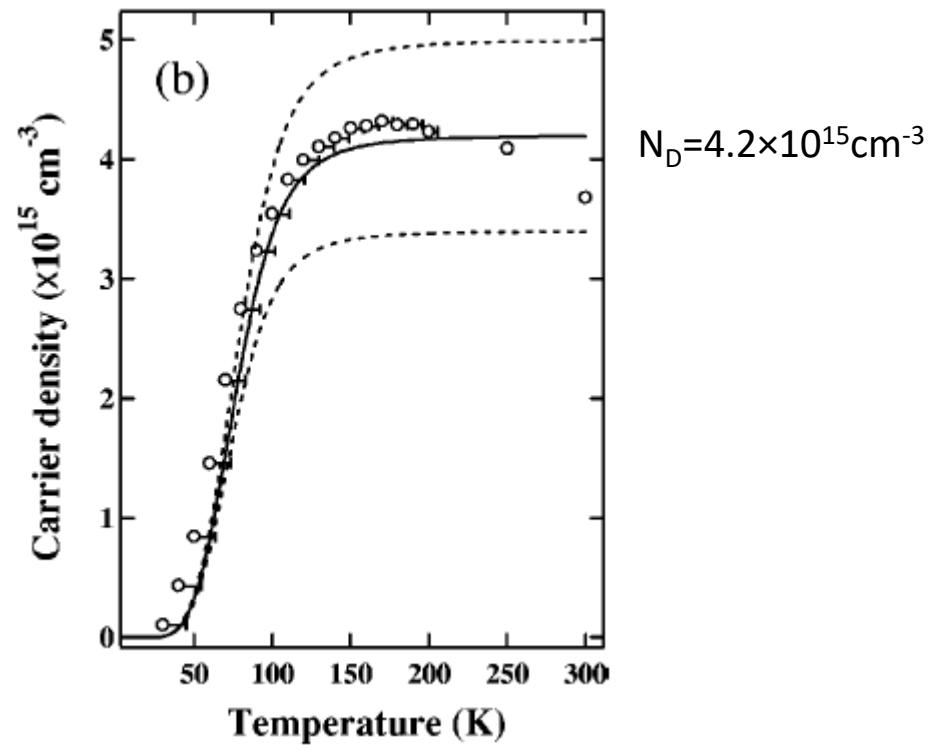
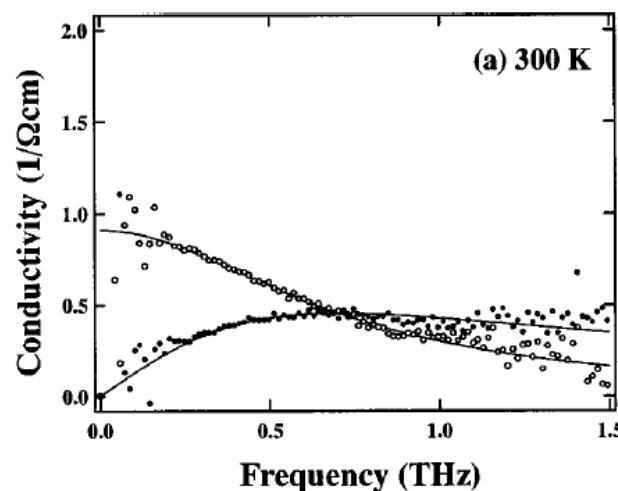
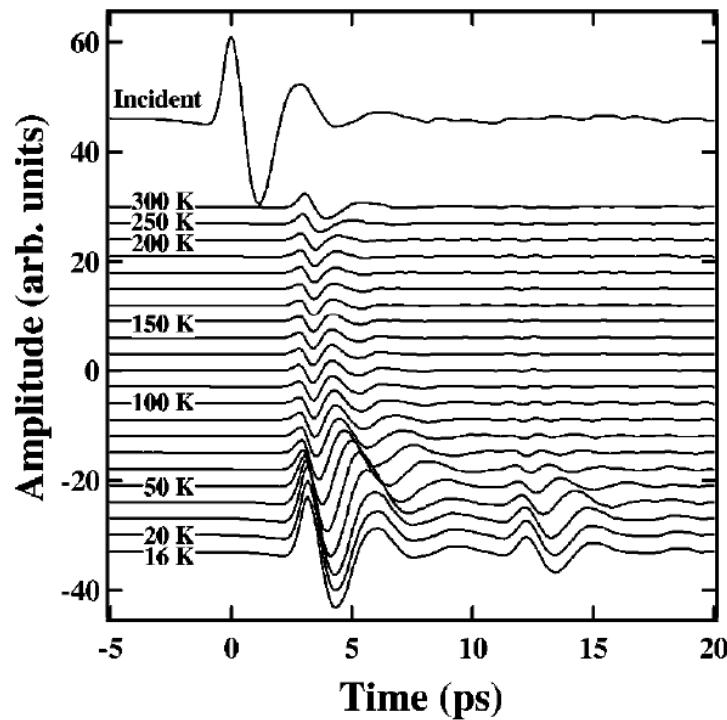
High-resolution (~1GHz)

THz spectroscopy:



# Wireless testing of doped semiconductors

Doped p-Si wafer

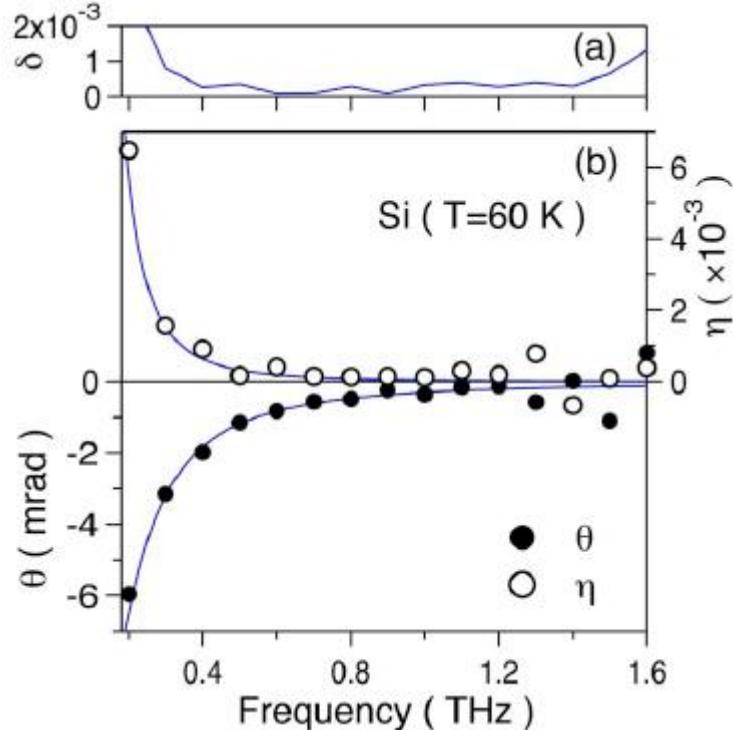
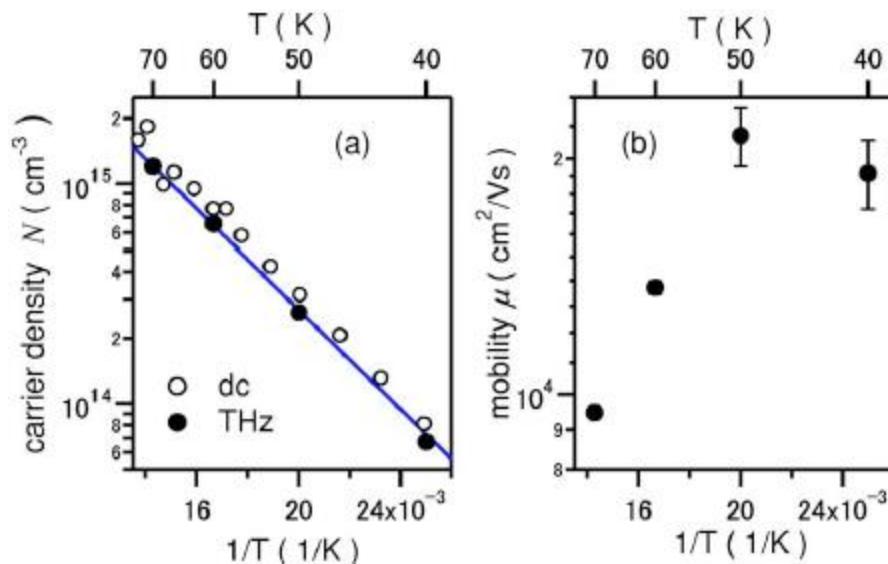


# Wireless testing of doped semiconductors

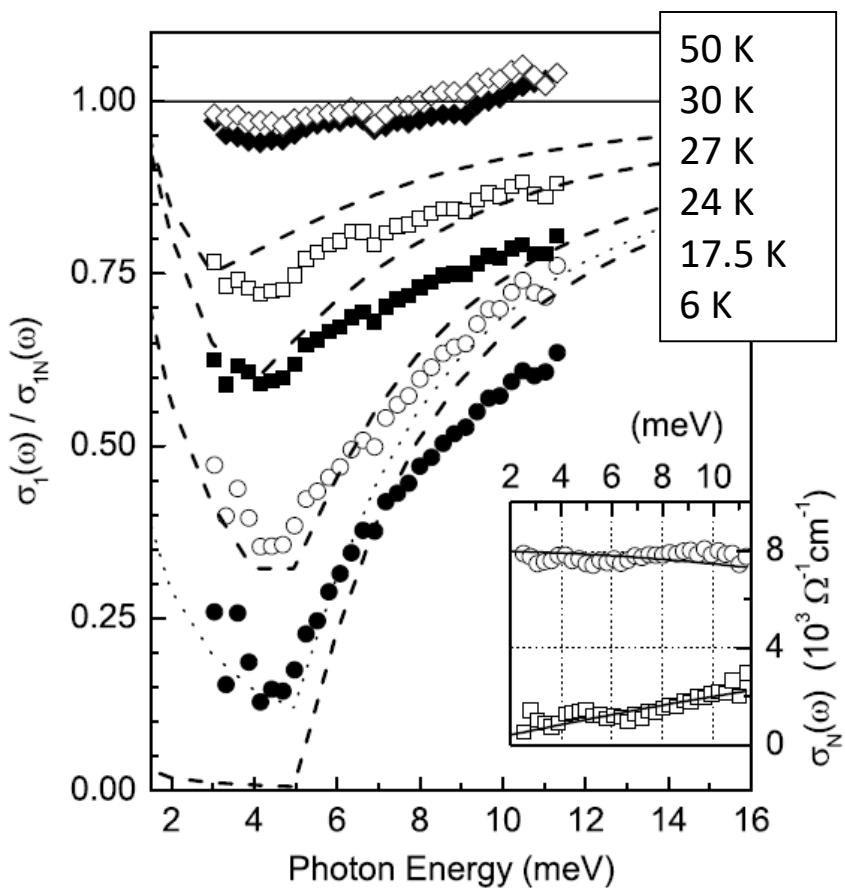
Doped n-Si wafer

$$E_y(\omega, B) \approx E_0(\omega) \exp \left[ -i\omega \left( t - \frac{\hat{N}(0)}{c} d \right) \right] \times (\sin \theta + i\eta \cos \theta) = E_x(\omega, 0) (\sin \theta + i\eta \cos \theta),$$

$$\theta + i\eta = -\frac{\omega}{2c} \frac{i\epsilon_{xy}}{\sqrt{\epsilon_{xx}}} d$$



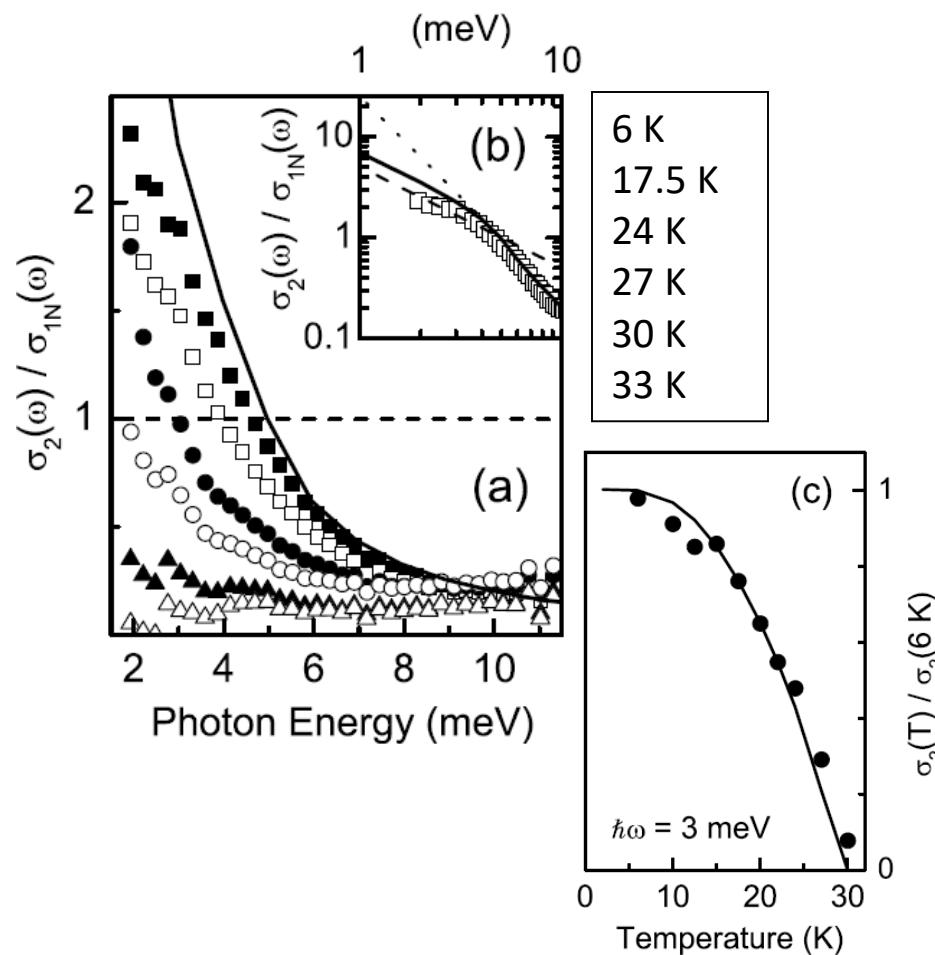
# Electrodynamics of superconductors: MgB<sub>2</sub>



BCS fit:  $2\Delta_0 = 5$  meV

Weak coupling:  $2\Delta_0 = 3.5k_B T_C = 9$  meV

Quasiparticle excitations below the gap



# Metamaterials in the THz range

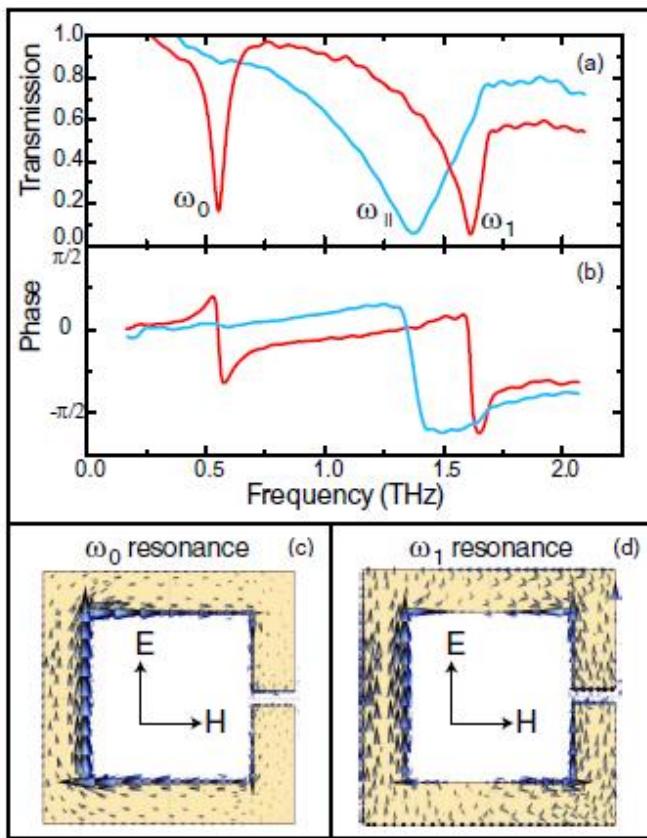
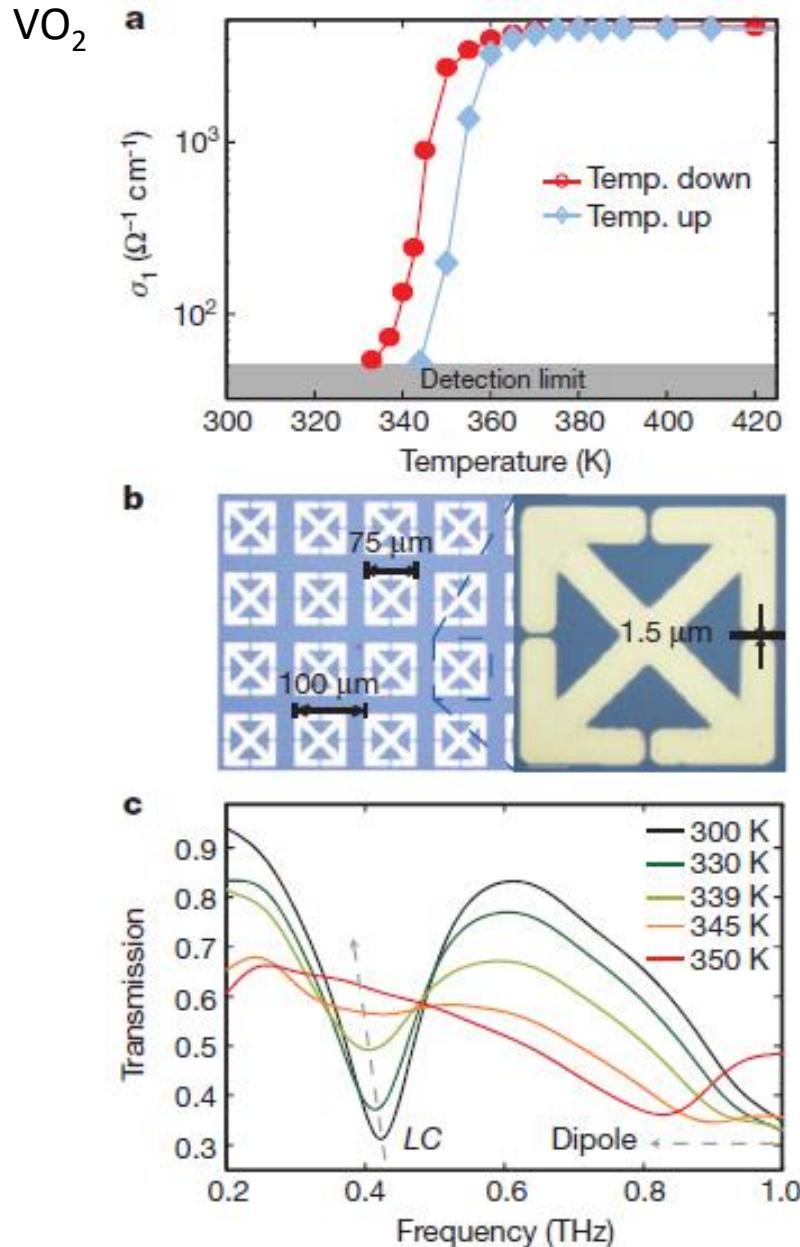
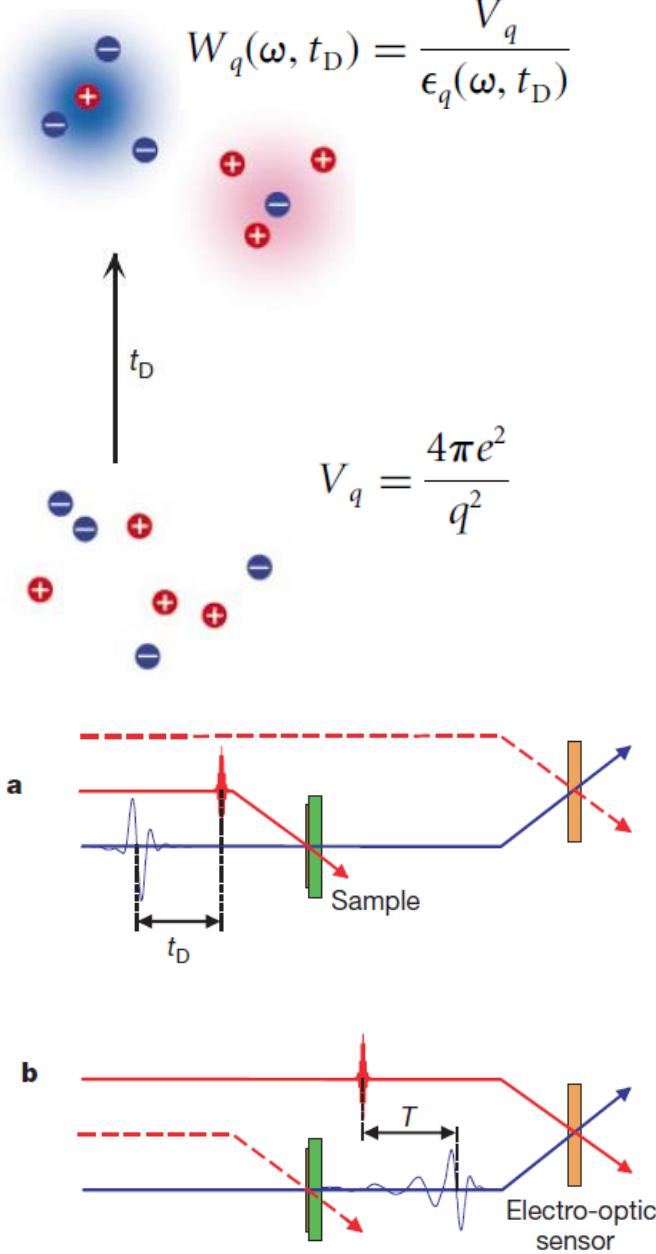


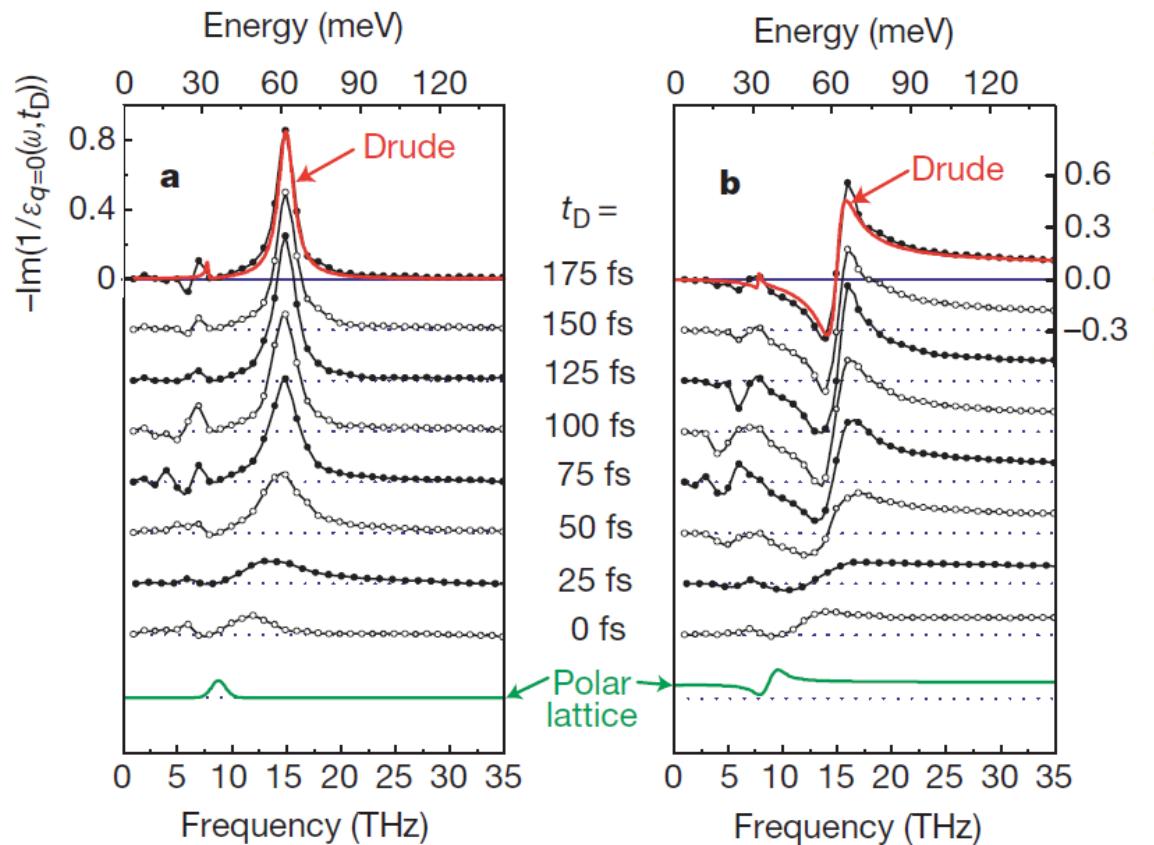
FIG. 1 (color online). The frequency dependent transmission spectra  $T(\omega)$  of the SRR sample is shown in (a), and in (b) the corresponding phase of the transmission is shown. In (a) and (b), the electric field is perpendicular to the SRR gap [red (dark) curves] and parallel to the SRR gap [blue (light) curves] at normal incidence. (c) and (d) are the surface current densities for the  $\omega_0$  (0.5 THz) and  $\omega_1$  (1.6 THz) resonances, respectively, as calculated by simulation. See the text for details.



# Time-resolved study of a Coulomb gas

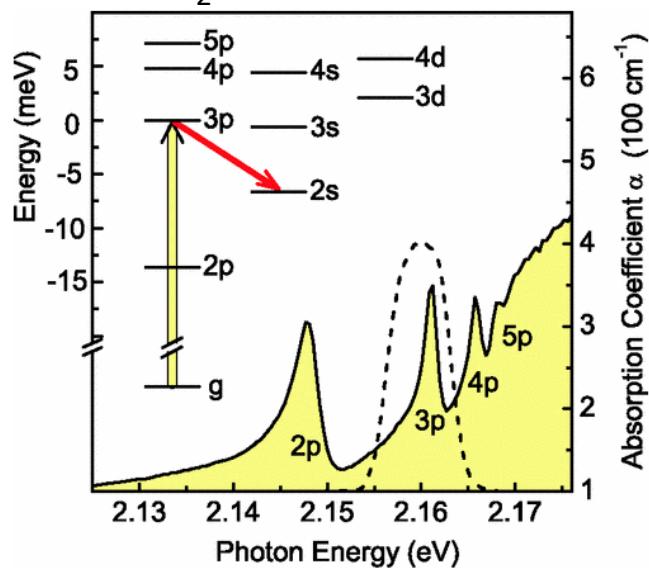


NIR pump – THz probe spectroscopy

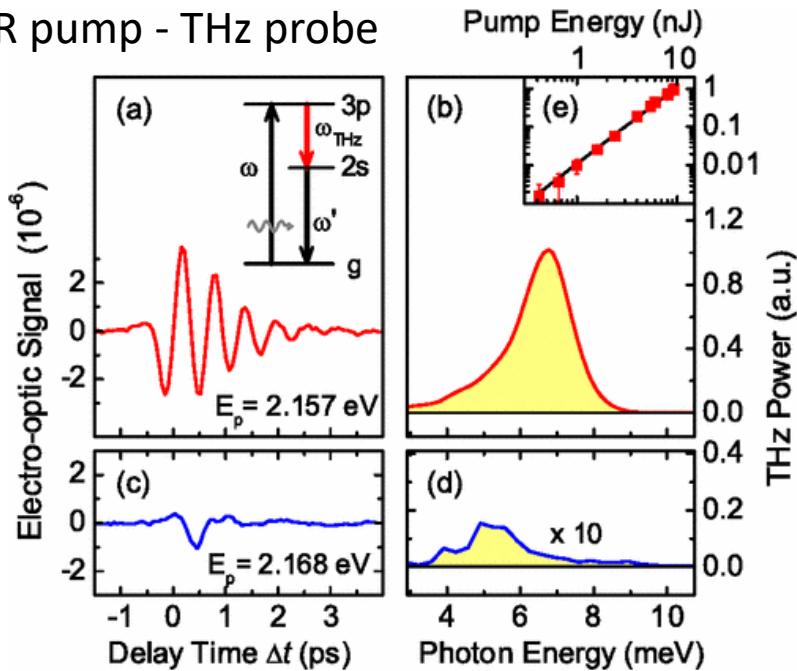


# Stimulated THz emission from excitations

Excitations in  $\text{Cu}_2\text{O}$



NIR pump - THz probe



THz response at  $\Delta t=1$  ps

Stimulated emission:

